## HMIC $^{\text {TM }}$ Silicon PIN Diode Switches RoHs Compliant

## Features

- Broad Bandwidth
- Specified from 50 MHz to 20 GHz
- Usable from 50 MHz to 26.5 GHz
- Lower Insertion Loss / Higher Isolation than pHempt
- Rugged
- Fully Monolithic,
- Glass Encapsulated Construction
- Up to +33dBm C.W. Power Handling

MASW-001100-1190

## Description

The MASW-001100-1190, MASW-002100-1191 and MASW-003100-1192 are broadband monolithic switches using series and shunt connected silicon PIN diodes. They are designed for use as 2 W , high performance switches in applications up to 26.5 GHz . They provide performance levels superior to those realized by hybrid MIC designs incorporating beamlead and PIN chip diodes that require chip and wire assembly.

These switches are fabricated using M/A-COM's patented HMIC ${ }^{\text {TM }}$ (Heterolithic Microwave Integrated Circuit) process, US Patent $5,268,310$. This process allows the incorporation of silicon pedestals that form series and shunt diodes or vias by imbedding them in low loss, low dispersion glass. By using small spacing between elements, this combination
 of silicon and glass gives HMIC devices low loss and high isolation performance through low millimeter frequencies.

Large bond pads facilitate the use of low inductance ribbon leads, while gold backside metallization allows for manual or automatic chip bonding via 80/20, AuSn solder or conductive Ag epoxy.

| Parameter | Absolute Maximum |
| :--- | :---: |
| Operating Temperature | $-65^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| Storage Temperature | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Junction Temperature | $+175^{\circ} \mathrm{C}$ |
| Applied Reverse Voltage | $1-50 \mathrm{~V} \mid$ |
| RF C.W. Incident Power | +33 dBm C.W. |
| Bias Current $+25^{\circ} \mathrm{C}$ | $\pm 20 \mathrm{~mA}$ |

## Max operating Conditions for a Combination of RF Power, D.C. Bias and Temperature: <br> +33 dBm CW @ 15mA (per diode) @+85 ${ }^{\circ} \mathrm{C}$

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HMIC $^{\text {M }}$ Silicon PIN Diode Switches
RoHs Compliant
MASW-001100-1190 (SPST)
Electrical Specifications @ $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}, 20 \mathrm{~mA}$ Bias

| Parameter | Frequency | Minimum | Nominal | Maximum | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | 6 GHz | - | 0.4 | 0.7 | dB |
| Insertion Loss | 13 GHz | - | 0.5 | 0.9 | dB |
|  | 20 GHz | - | 0.7 | 1.2 | dB |
|  | 6 GHz | 46 | 55 | - | dB |
| Isolation | 13 GHz | 39 | 47 | - | dB |
|  | 20 GHz | 34 | 42 | - | dB |
|  | 6 GHz | 22 | 31 | - | dB |
| Input Return Loss | 13 GHz | 15 | 33 | - | dB |
| Switching Speed ${ }^{1}$ | 20 GHz | 14 | 27 | - | dB |
| Voltage Rating ${ }^{2}$ | - | - | 20 | - | ns |
| Signal Compression $(500 \mathrm{~mW})$ | 1 GHz | - | - | 50 | V |

1.) Typical Switching Speed measured from $10 \%$ to $90 \%$ of detected RF signal driven by TTL compatible drivers.
2.) Maximum reverse leakage current in either the shunt or series PIN diodes shall be 10 mA maximum at -50 volts.

| Parameter | Frequency | Minimum | Nominal | Maximum | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | 6 GHz | - | 0.4 | 0.7 | dB |
| Insertion Loss | 13 GHz | - | 0.5 | 1.0 | dB |
|  | 20 GHz | - | 0.7 | 1.2 | dB |
|  | 6 GHz | 48 | 63 | - | dB |
| Isolation | 13 GHz | 40 | 50 | - | dB |
|  | 20 GHz | 34 | 42 | - | dB |
|  | 6 GHz | 20 | 27 | - | dB |
| Input Return Loss | 13 GHz | 18 | 25 | - | dB |
| Switching Speed ${ }^{1}$ | 20 GHz | 15 | 25 | - | dB |
| Voltage Rating ${ }^{2}$ | - | - | 20 | ns |  |
| Signal Compression $(500 \mathrm{~mW})$ | 1 GHz | - | - | 50 | V |

1.) Typical Switching Speed measured from $10 \%$ to $90 \%$ of detected RF signal driven by TTL compatible drivers.
2.) Maximum reverse leakage current in either the shunt or series PIN diodes shall be 10 mA maximum at -50 volts.

MASW-003100-1192 (SP3T)
Electrical Specifications @ $\mathrm{T}_{\mathrm{A}}=+\mathbf{2 5 ^ { \circ }} \mathrm{C}, \mathbf{2 0 m A}$ Bias

| Parameter | Frequency | Minimum | Nominal | Maximum | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | 6 GHz | - | 0.5 | 0.8 | dB |
| Insertion Loss | 13 GHz | - | 0.7 | 1.1 | dB |
|  | 20 GHz | - | 0.9 | 1.5 | dB |
|  | 6 GHz | 49 | 57 | - | dB |
| Isolation | 13 GHz | 42 | 48 | - | dB |
|  | 20 GHz | 33 | 42 | - | dB |
|  | 6 GHz | 20 | 24 | - | dB |
| Input Return Loss | 13 GHz | 14 | 22 | - | dB |
|  | 20 GHz | 11 | 21 | - | dB |
| Switching Speed ${ }^{1}$ | - | - | 20 | - | ns |
| Voltage Rating ${ }^{2}$ | - | - | - | 50 | V |
| Signal Compression $(500 \mathrm{~mW})$ | 1 GHz | - | 0.2 | - | dB |

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HMIC $^{\text {M }}$ Silicon PIN Diode Switches

Typical Performance Curves at $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}, 20 \mathrm{~mA}$ Bias Current


S-Parameters: S-Parameter data for these devices are available upon request.

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HMIC $^{\text {M }}$ Silicon PIN Diode Switches
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Typical Performance Curves @ $\mathrm{TA}=+25^{\circ} \mathrm{C}, 20 \mathrm{~mA}$ Bias Current


MASW-002100-1191 ISOLATION vs. FREQUENCY


MASW-003100-1192
ISOLATION vs. FREQUENCY



OUTPUT RETURN LOSS vs. BIAS CURRENT@ 10 GHz


INSERTION LOSS vs. BIAS CURRENT @ 10 GHz


ISOLATION vs. BIAS CURRENT @ 10 GHz


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HMIC ${ }^{\text {TM }}$ Silicon PIN Diode Switches

## Operation of the MASW Series Switches

Operation of the MASW series of PIN switches is achieved by simultaneous application of negative DC current to the low loss switching arm $\mathrm{J} 1, \mathrm{~J} 2$, or J 3 , and positive DC current to the remaining switching arms as shown in the bias connection circuits. DC return is achieved via J 1 . The control currents should be supplied by constant current sources. The voltages at these points will not exceed $\pm 1.5$ volts ( 1.2 V typical) at currents up to $\pm 20 \mathrm{~mA}$. In the low loss state, the series diode must be forward biased and the shunt diode reverse biased. In the isolated arm, the shunt diode is forward biased and the series diode is reverse biased.

## Driver Connections <br> MASW-001100-1190

| Control Level <br> (DC Current) at | Condition of <br> RF Output |
| :---: | :---: |
| J2 | J1-J2 |
| -20 mA | Low Loss |
| +20 mA | Isolation |

MASW-002100-1191

| Control Level <br> (DC Current) at |  | Condition of <br> RF Output | Condition of <br> RF Output |
| :---: | :---: | :---: | :---: |
| J2 | J3 | J1-J2 | J1-J3 |
| -20 mA | +20 mA | Low Loss | Isolation |
| +20 mA | -20 mA | Isolation | Low Loss |

MASW-003100-1192

| Control Level <br> (DC Current) at |  | Cond. of <br> RF Output | Cond. of <br> RF Output | Cond. of RF <br> Output |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| J 2 | J 3 | J 4 | $\mathrm{~J} 1-\mathrm{J} 2$ | $\mathrm{~J} 1-\mathrm{J} 3$ | $\mathrm{~J} 1-\mathrm{J} 4$ |
| -20 mA | +20 mA | +20 mA | Low Loss | Isolation | Isolation |
| +20 mA | -20 mA | +20 mA | Isolation | Low Loss | Isolation |
| +20 mA | +20 mA | -20 mA | Isolation | Isolation | Low Loss |

## Handling Considerations

Cleanliness: These chips should be handled in a clean environment.
Electro-Static Sensitivity: The MASW series PIN switches are ESD, Class 1A sensitive (HBM). The proper ESD handling procedures should be used.

MASW-001100-1190 and Bias Connections ${ }^{1}$


MASW-002100-1191 and Bias Connections ${ }^{1}$


MASW-003100-1192 and Bias Connections ${ }^{1}$


Notes:

1. RLC values are for an operation frequency of $2-18 \mathrm{GHz}$ and bias current of $\pm 20 \mathrm{~mA}$ per diode.

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## Wire Bonding

Thermosonic wedge wire bonding using $0.003^{\prime \prime} \times 0.00025^{\prime \prime}$ ribbon or $0.001^{\prime \prime}$ diameter gold wire is recommended. A heat stage temperature of approximately $200^{\circ} \mathrm{C}$ and a force of 18 to 22 grams should be used. Ultrasonic energy should be adjusted to the minimum required to achieve a good bond. RF bond wires should be kept as short as possible.

## Mounting

The HMIC switches have TiPtAu back metal. They can be die mounted with a gold-tin eutectic solder preform or conductive epoxy. Mounting surface must be clean and flat.

Eutectic Die Attachment: An 80/20 gold-tin eutectic solder preform is recommended with a work surface temperature of $255^{\circ} \mathrm{C}$ and a tool tip temperature of $265^{\circ} \mathrm{C}$. When hot gas is applied, the tool tip temperature should be $290^{\circ} \mathrm{C}$. The chip should not be exposed to temperatures greater than $320^{\circ} \mathrm{C}$ for more than 20 seconds. No more than three seconds should be required for attachment. Solders containing tin should not be used.

Epoxy Die Attachment: Surface of assembly should be preheated to $125-150^{\circ} \mathrm{C}$. A minimum amount of epoxy should be used. A thin epoxy fillet should be visible around the perimeter of the chip after placement. Cure epoxy per manufacturer's schedule.

## Chip Outline Drawing ${ }^{1,2}$



| DIM | INCHES |  | MM |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | MAX. | MIN. | MAX. |  |  |
| A | 0.014 | 0.018 | 0.35 | 0.45 |  |  |
| B | 0.025 | 0.029 | 0.64 | 0.74 |  |  |
| C | 0.008 REF |  | 0.20 REF |  |  |  |
| D | 0.004 |  | 0.006 | 0.10 |  | 0.15 |
| E | 0.004 REF |  | 0.10 REF |  |  |  |
| F | 0.003 REF |  | 0.08 REF |  |  |  |
| G | 0.003 REF |  | 0.08 REF |  |  |  |
| H | 0.020 REF |  | 0.52 |  |  |  |

## Notes:

1. Topside and backside surface metallization is gold, $2.5 \mu \mathrm{~m}$ thick typical.
2. Yellow areas indicate wire bonding pads.

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# Chip Outline Drawing ${ }^{1,2}$ 

## MASW-002100-1191


(A) SQ.


| DIM | INCHES |  | MM |  |
| :---: | :---: | :---: | :---: | :---: |
|  | MIN. | MAX. | MIN. | MAX. |
| A | 0.029 | 0.033 | 0.73 | 0.83 |
| B | 0.004 | 0.006 | 0.10 | 0.15 |
| C | 0.004 REF |  | 0.10 REF |  |
| D | 0.005 REF |  | 0.13 REF |  |
| E | 0.009 REF |  | 0.23 REF |  |
| F | 0.58 REF |  |  |  |
| G | 0.023 REF |  | 0.17 REF |  |
| H | 0.10 REF |  |  |  |

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## Chip Outline Drawing ${ }^{1,2}$

## MASW-003100-1192



| DIM | INCHES |  | MM |  |
| :---: | :---: | :---: | :---: | :---: |
|  | MIN. | MAX. | MIN. | MAX. |
| A | 0.046 | 0.050 | 1.16 | 1.26 |
| B | 0.036 | 0.040 | 0.92 | 1.02 |
| C | 0.019 REF |  | 0.48 REF |  |
| D | 0.014 REF |  | 0.36 REF |  |
| E | 0.004 REF |  | 0.10 REF |  |
| F | 0.005 REF |  | 0.13 REF |  |
| G | 0.004 |  | 0.006 | 0.15 |
| H | 0.005 REF |  | 0.12 REF |  |
| J | 0.004 REF |  |  |  |

Notes:

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## Ordering Information

| Part Number | Package |
| :---: | :---: |
| MASW-001100-11900W | Waffle Pack |
| MASW-001100-11900G | Gel Pack |
| MASW-002100-11910W | Waffle Pack |
| MASW-002100-11910G | Gel Pack |
| MASW-003100-11920W | Waffle Pack |
| MASW-003100-11920G | Gel Pack |

